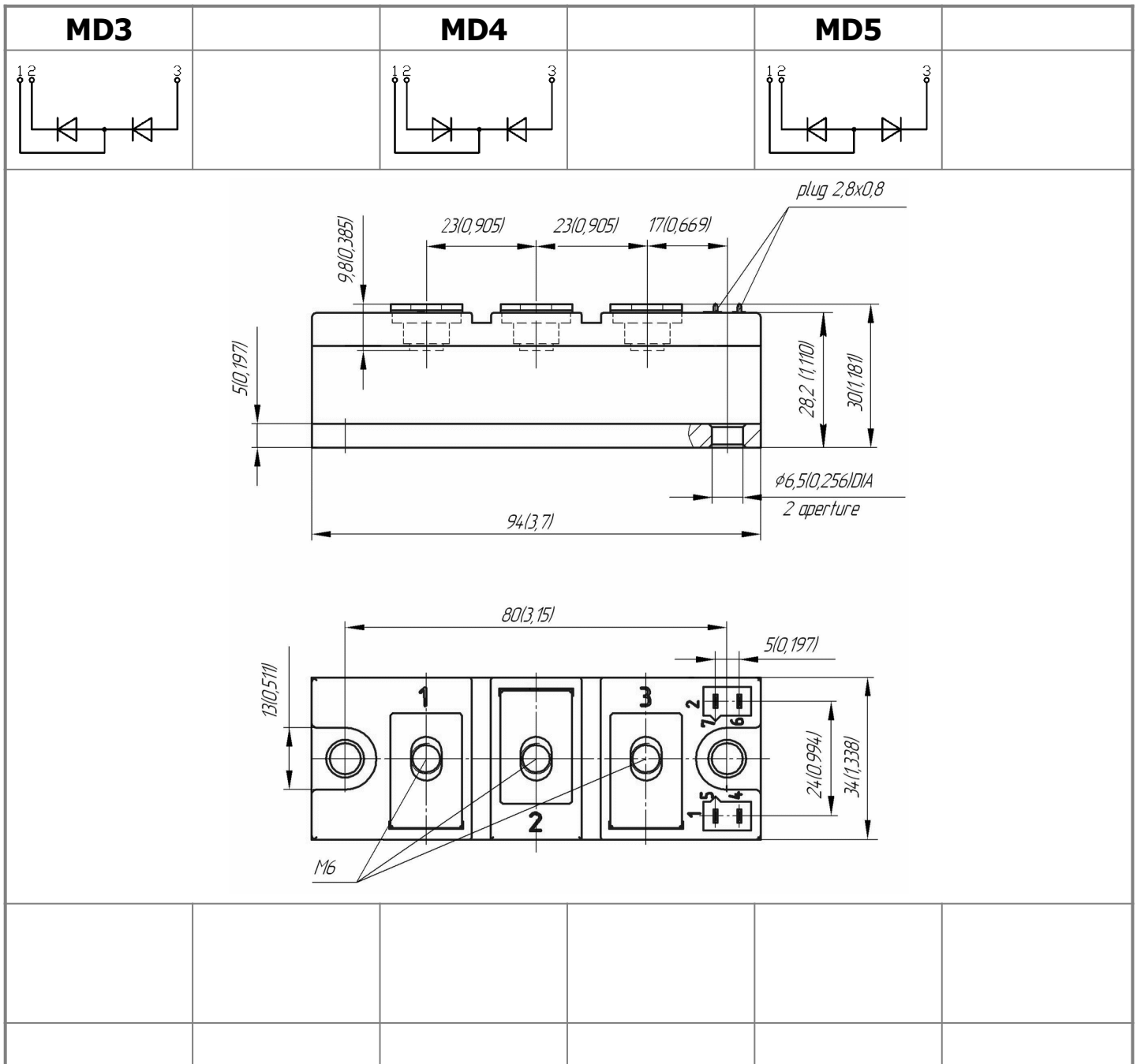




Double Diode Module
For Phase Control
MDx-175-28-F

Electrically isolated base plate
Industrial standard package
Simplified mechanical design, rapid assembly
Pressure contact

Average forward current		I_{FAV}	175 A
Repetitive peak reverse voltage		V_{RRM}	2400 ÷ 2800 V
V_{RRM} , V	2400	2600	2800
Voltage code	24	26	28
T_j , °C	- 40 ÷ 150		



All dimensions in millimeters (inches)


MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions
ON-STATE				
I_{FAV}	Average forward current	A	175	$T_c = 100\text{ }^\circ\text{C}$;
I_{FRMS}	RMS forward current	A	275	180° half-sine wave; 50 Hz
I_{FSM}	Surge forward current	kA	6.0 7.0	$T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 10\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
			6.5 7.5	$T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 8.3\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
I^2t	Safety factor	$A^2s \cdot 10^3$	180 240	$T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 10\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
			170 230	$T_j = T_{j\text{ max}}$ $T_j = 25\text{ }^\circ\text{C}$ 180° half-sine wave; $t_p = 8.3\text{ ms}$; single pulse; $V_R = 0\text{ V}$;
BLOCKING				
V_{RRM}	Repetitive peak reverse voltages	V	2400÷2800	$T_{j\text{ min}} < T_j < T_{j\text{ max}}$; 180° half-sine wave; 50 Hz;
V_{RSM}	Non-repetitive peak reverse voltages	V	2500÷2900	$T_{j\text{ min}} < T_j < T_{j\text{ max}}$; 180° half-sine wave; single pulse;
V_R	Reverse continuous voltages	V	$0.6 \cdot V_{RRM}$	$T_j = T_{j\text{ max}}$;
THERMAL				
T_{stg}	Storage temperature	$^\circ\text{C}$	- 40 ÷ 50	
T_j	Operating junction temperature	$^\circ\text{C}$	- 40 ÷ 150	
$T_{c\text{ op}}$	Operating temperature	$^\circ\text{C}$	- 40 ÷ 125	
MECHANICAL				
a	Acceleration under vibration	m/s^2	50	

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
ON-STATE				
V_{FM}	Peak forward voltage, max	V	1.50	$T_j = 25\text{ }^\circ\text{C}$; $I_{FM} = 500\text{ A}$
$V_{F(TO)}$	Forward threshold voltage, max	V	0.85	$T_j = T_{j\text{ max}}$;
r_T	Forward slope resistance, max	$m\Omega$	1.500	$0.5 \pi I_{FAV} < I_T < 1.5 \pi I_{FAV}$
BLOCKING				
I_{RRM}	Repetitive peak reverse current, max	mA	35	$T_j = T_{j\text{ max}}$; $V_R = V_{RRM}$
SWITCHING				
Q_{rr}	Total recovered charge, max	μC	1250	$T_j = T_{j\text{ max}}$; $I_{FM} = 175\text{ A}$;
t_{rr}	Reverse recovery time, max	μs	24	$di_R/dt = -10\text{ A}/\mu\text{s}$;
I_{rrM}	Peak reverse recovery current, max	A	104	$V_R = 100\text{ V}$;
THERMAL				
R_{thjc}	Thermal resistance, junction to case			
	per module	$^\circ\text{C}/\text{W}$	0.0950	180° half-sine wave, 50 Hz
	per arm	$^\circ\text{C}/\text{W}$	0.1900	
	per module	$^\circ\text{C}/\text{W}$	0.0900	DC
per arm	$^\circ\text{C}/\text{W}$	0.1800		
R_{thch}	Thermal resistance, case to heatsink			
	per module	$^\circ\text{C}/\text{W}$	0.0300	
	per arm	$^\circ\text{C}/\text{W}$	0.0600	

INSULATION					
V _{ISOL}	Insulation test voltage	kV	3.00	Sine wave, 50 Hz; RMS	t=60 sec
			3.60		t=1 sec
MECHANICAL					
M ₁	Mounting torque (M6) ¹⁾	Nm	6.00	Tolerance ± 15%	
M ₂	Terminal connection torque (M6) ¹⁾	Nm	6.00	Tolerance ± 15%	
w	Weight, max	g	350		

PART NUMBERING GUIDE						NOTES					
MD	3	-	175	-	28	-	F	-	N		¹⁾ The screws must be lubricated
1	2		3		4		5		6		
1. MD - Rectifier Diode 2. Circuit Schematic 3. Average Forward Current, A 4. Voltage Code 5. Package Type (M.F) 6. Ambient Conditions: N – Normal											
		UL certified file-No. E255404									

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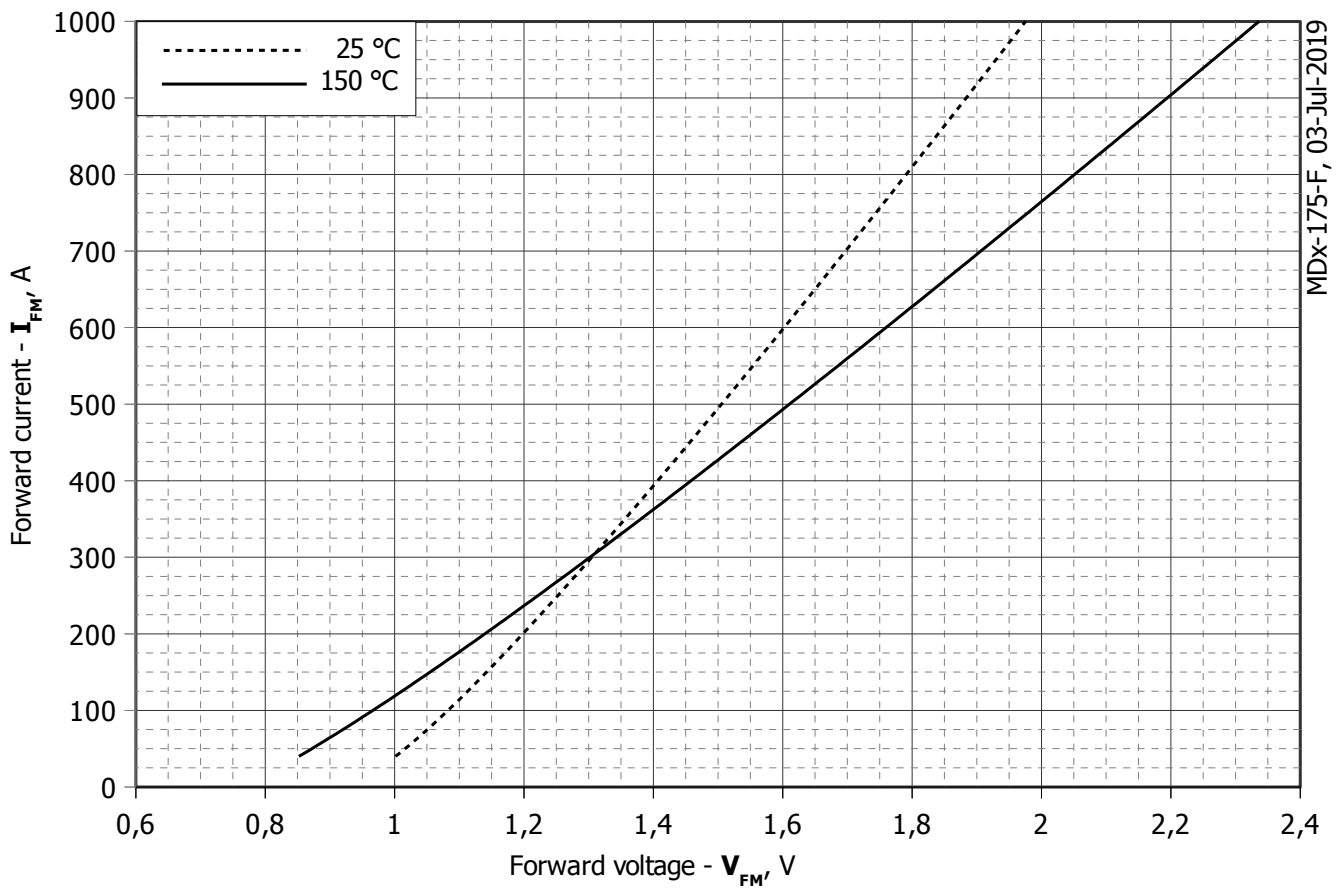


Fig 1 – Forward characteristics of Limit device

Analytical function for Forward characteristic:

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

	Coefficients for max curves	
	$T_j = 25^\circ\text{C}$	$T_j = T_{j\text{max}}$
A	0.9073700	0.7726702
B	0.0007684	0.0011635
C	0.0014373	-0.0202749
D	0.0091654	0.0170877

Forward characteristic model (see Fig. 1).

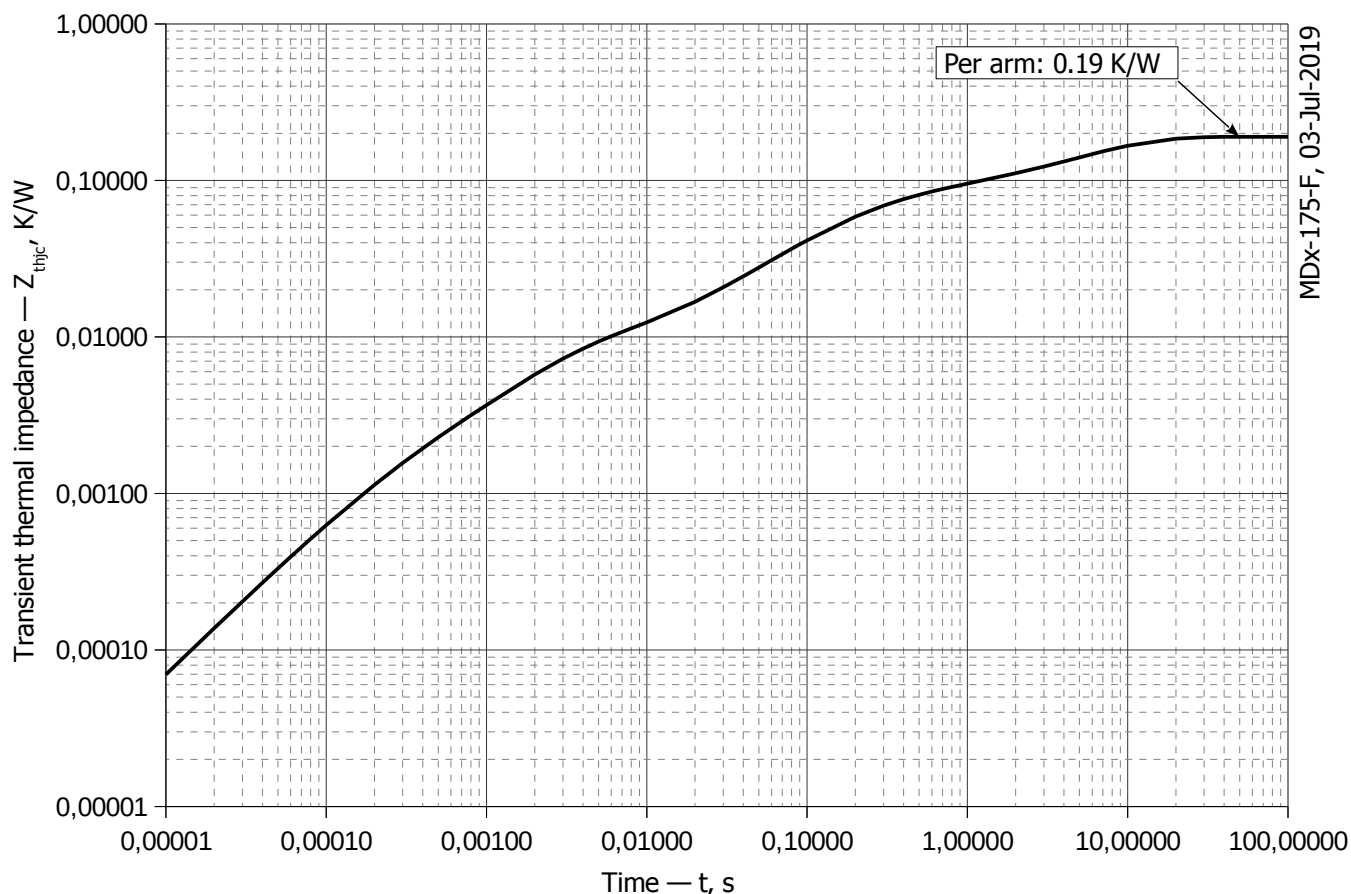


Fig 2 – Transient thermal impedance Z_{thjc} vs. time t

Analytical function for Transient thermal impedance junction to case Z_{thjc} for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left(1 - e^{-\frac{t}{\tau_i}} \right)$$

Where $i = 1$ to n , n is the number of terms in the series.

t = Duration of heating pulse in seconds.

Z_{thjc} = Thermal resistance at time t .

R_i = Amplitude of p_{th} term.

τ_i = Time constant of r_{th} term.

DC

i	1	2	3	4	5	6
R_i, K/W	0.0007824	0.007029	0.01292	0.04452	0.0191	0.1056
τ_i, s	0.0002166	0.002381	0.06714	0.1793	0.602	6.635

Transient thermal impedance junction to case Z_{thjc} model (see Fig. 2)

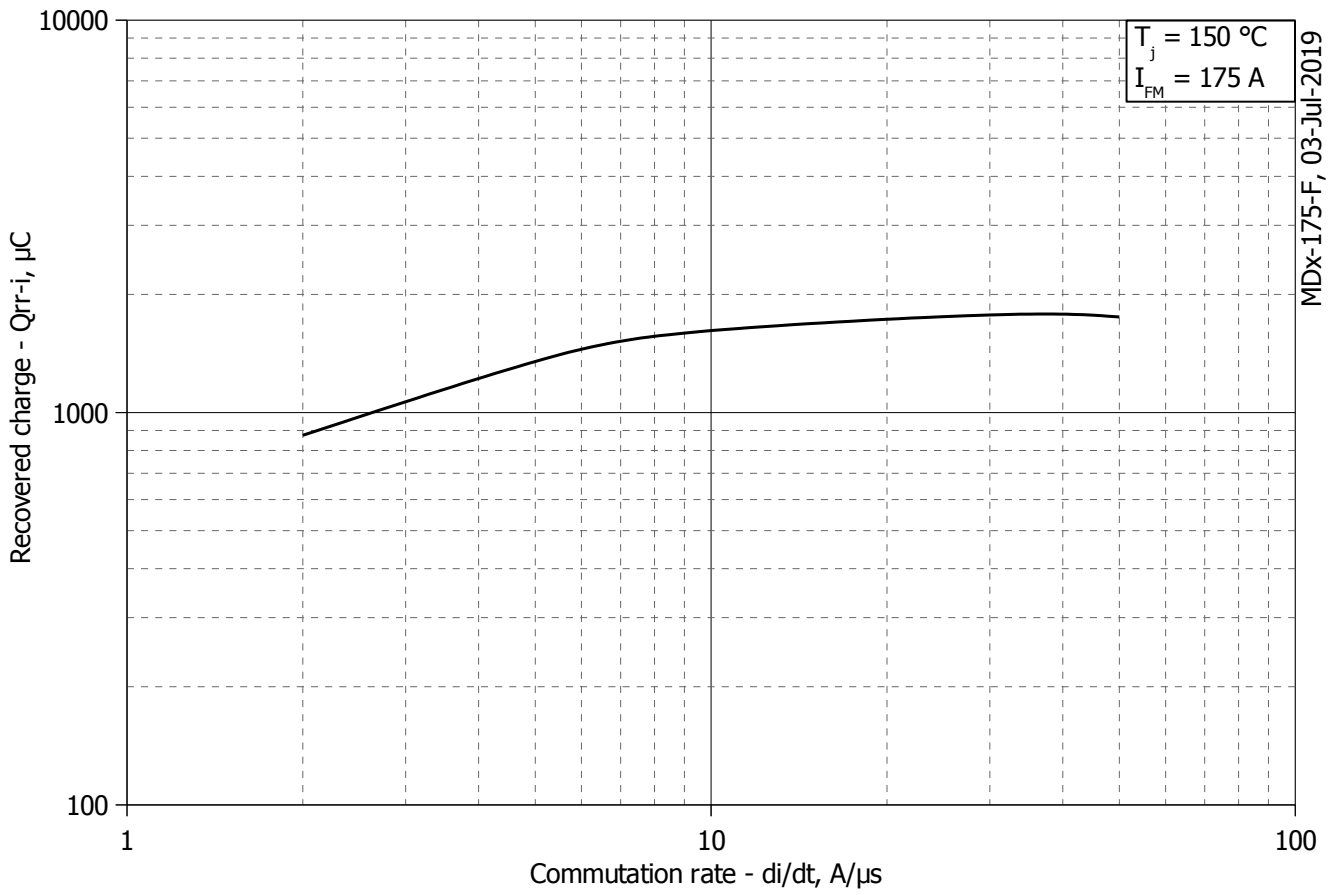


Fig 3 – Maximum recovered charge Q_{rr-i} (integral) vs. commutation rate di_R/dt

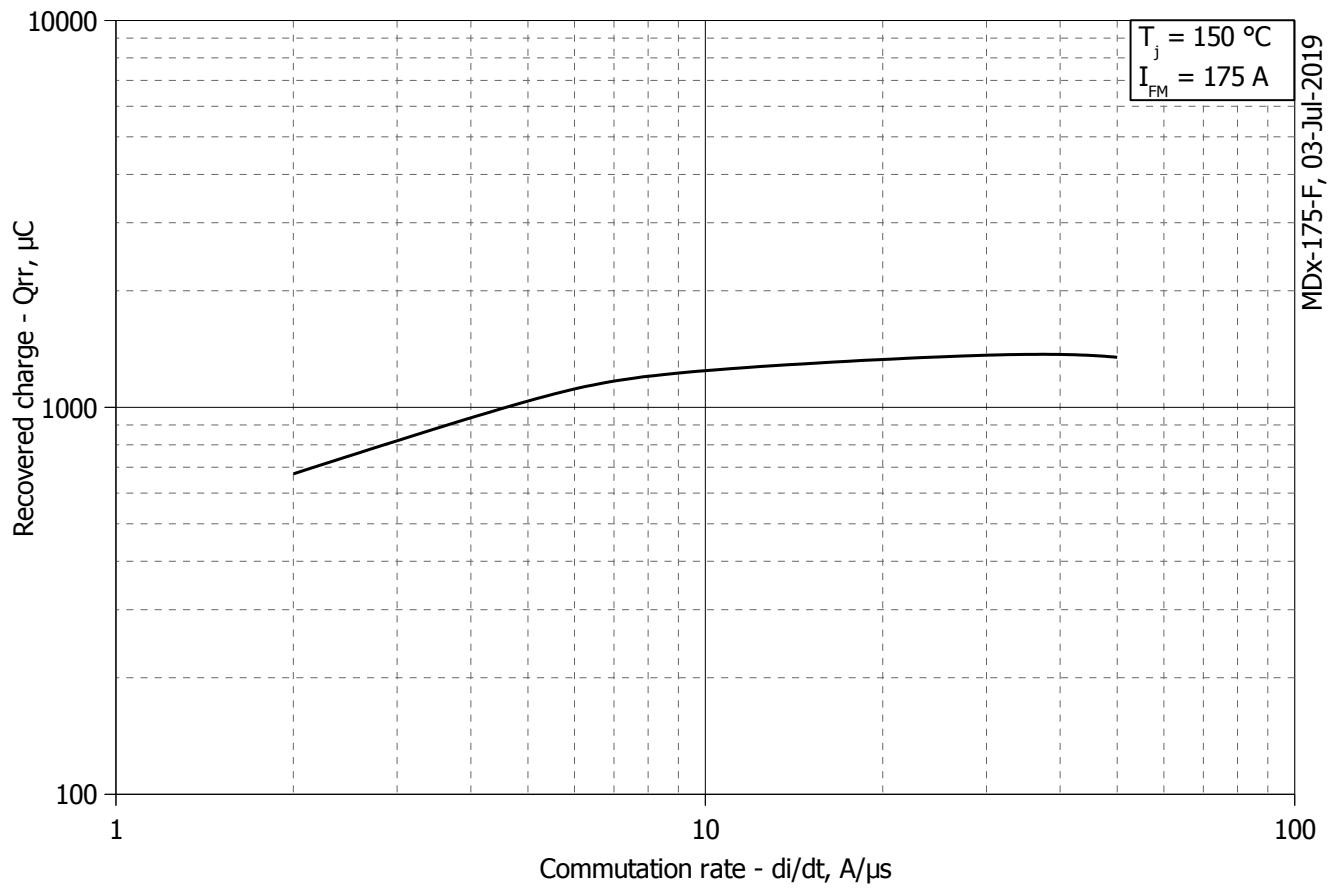


Fig 4 – Maximum recovered charge Q_{rr} vs. commutation rate di_R/dt (25% chord)

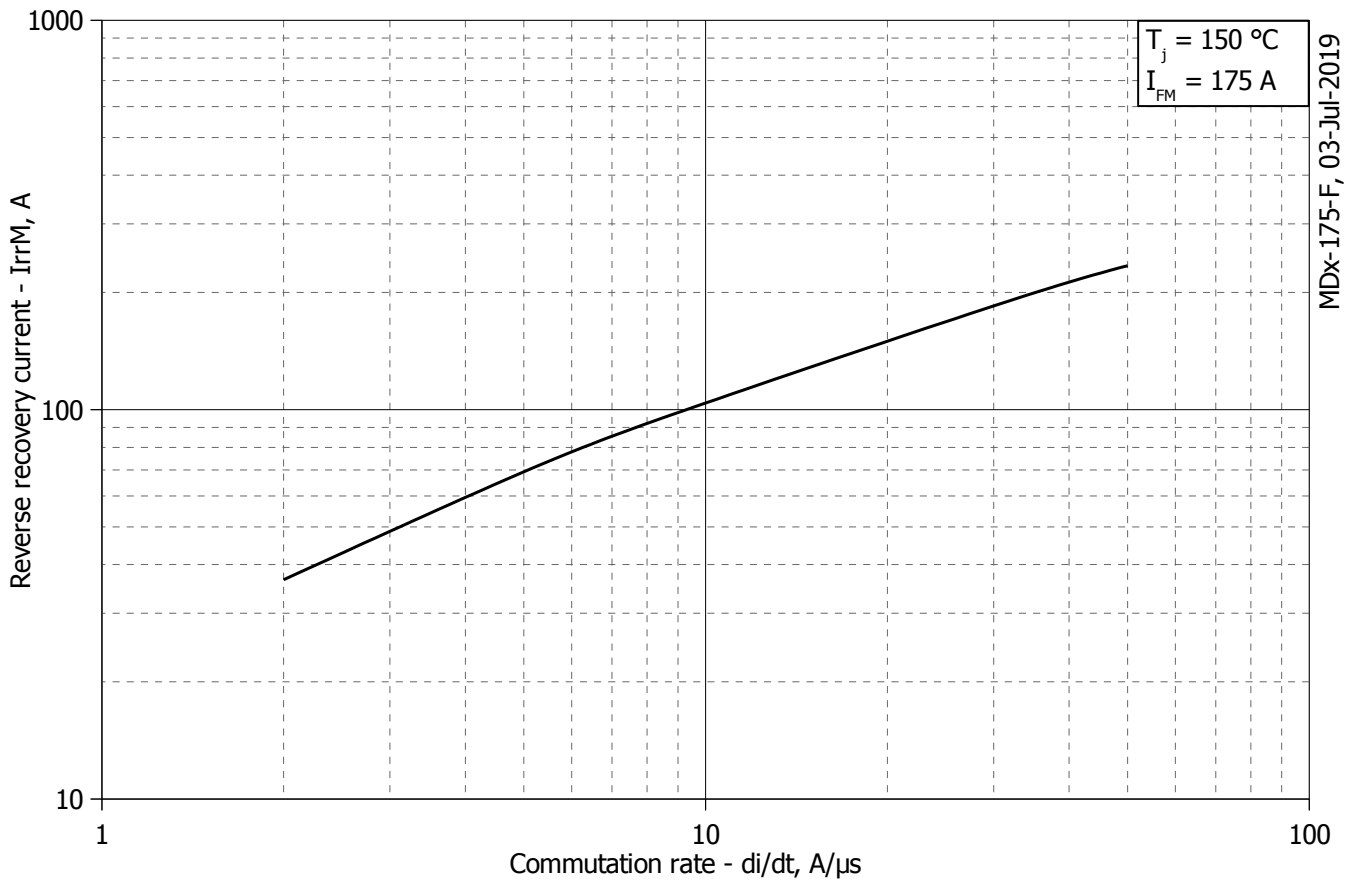


Fig 5 – Maximum reverse recovery current I_{rrM} vs. commutation rate di_R/dt

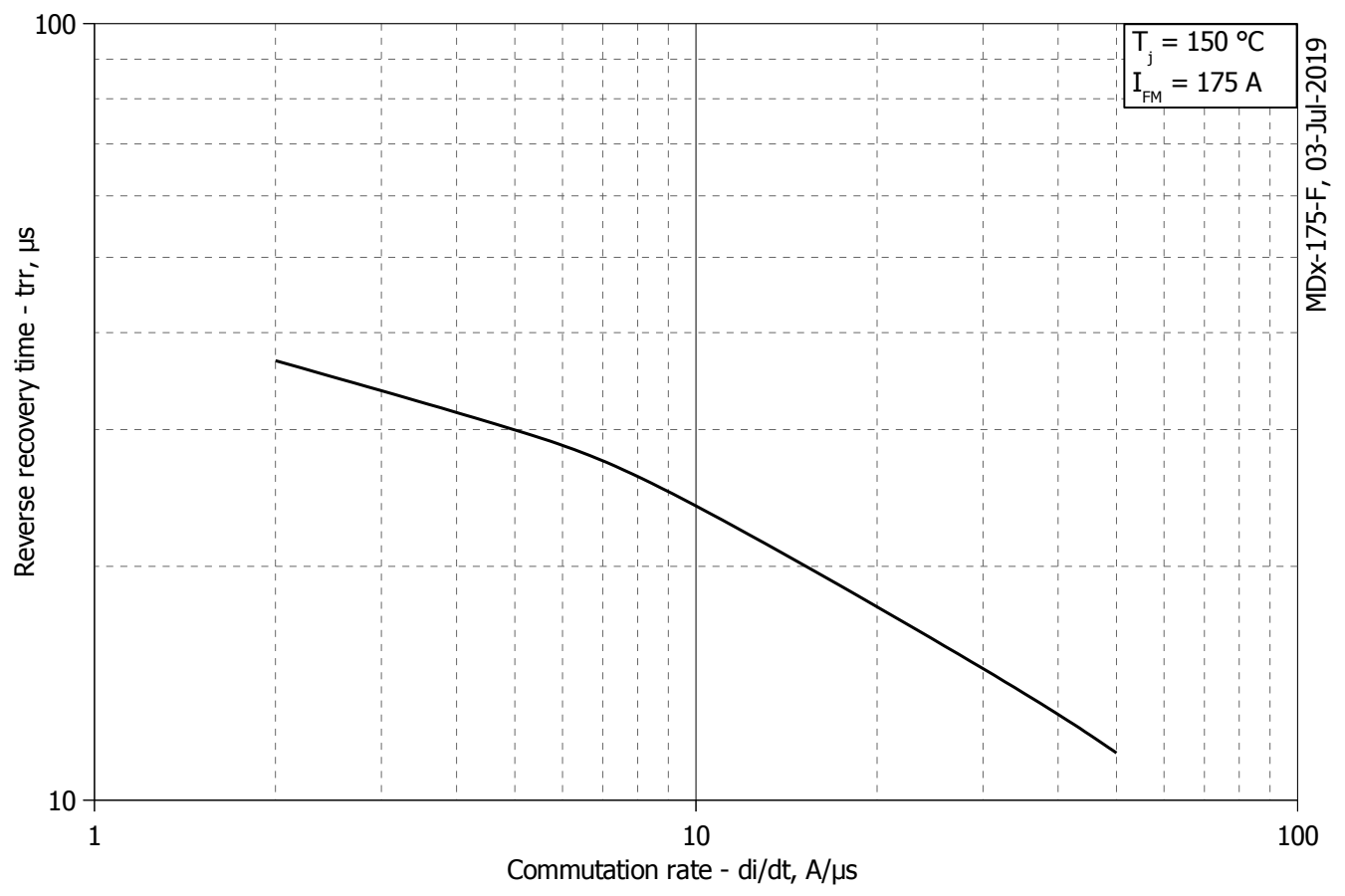


Fig 6 – Maximum recovery time t_{rr} vs. commutation rate di_R/dt (25% chord)

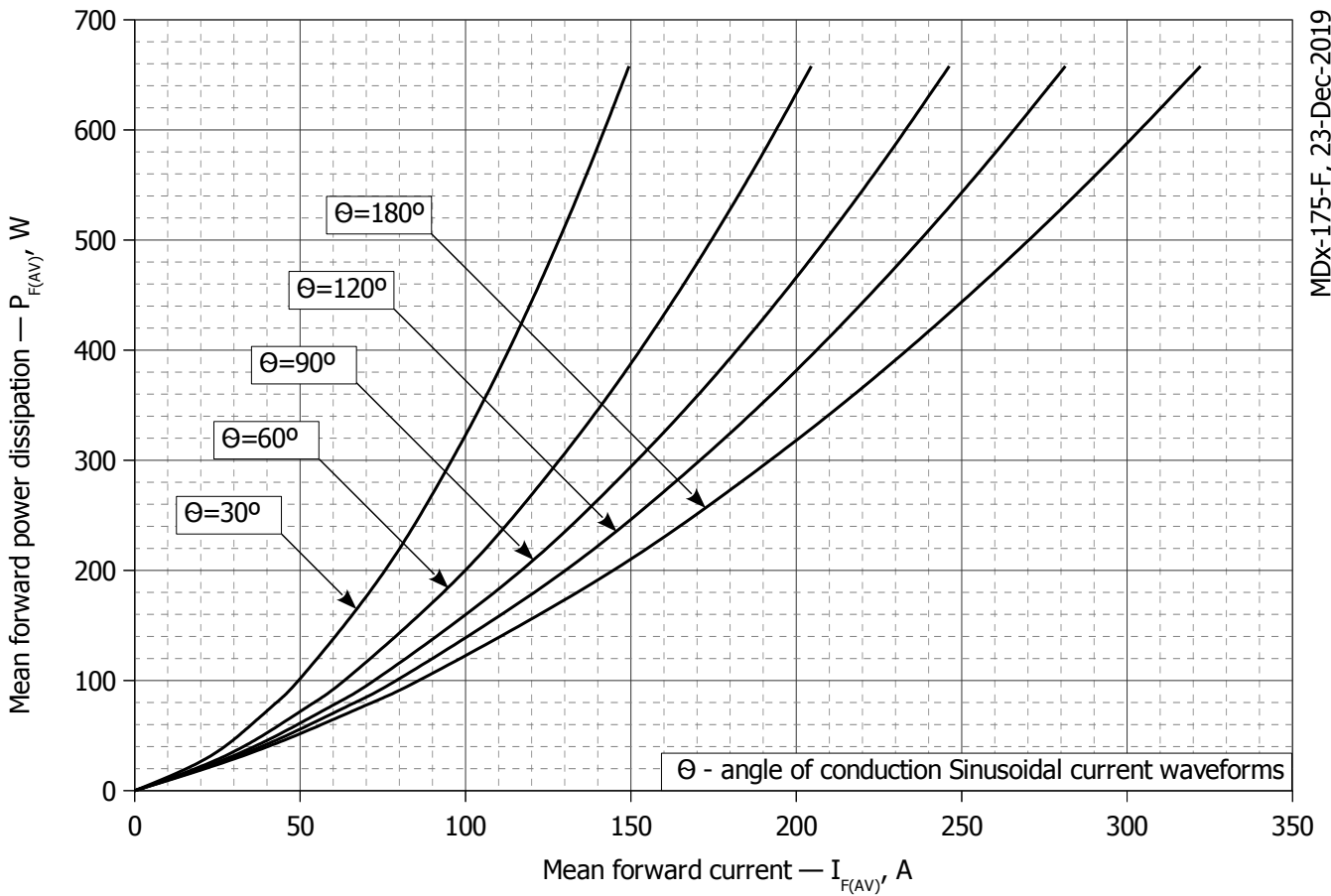


Fig. 7 - Mean forward power dissipation $P_{F(AV)}$ vs. mean forward current $I_{F(AV)}$ for sinusoidal current waveforms at different conduction angles ($f=50\text{Hz}$, DSC)

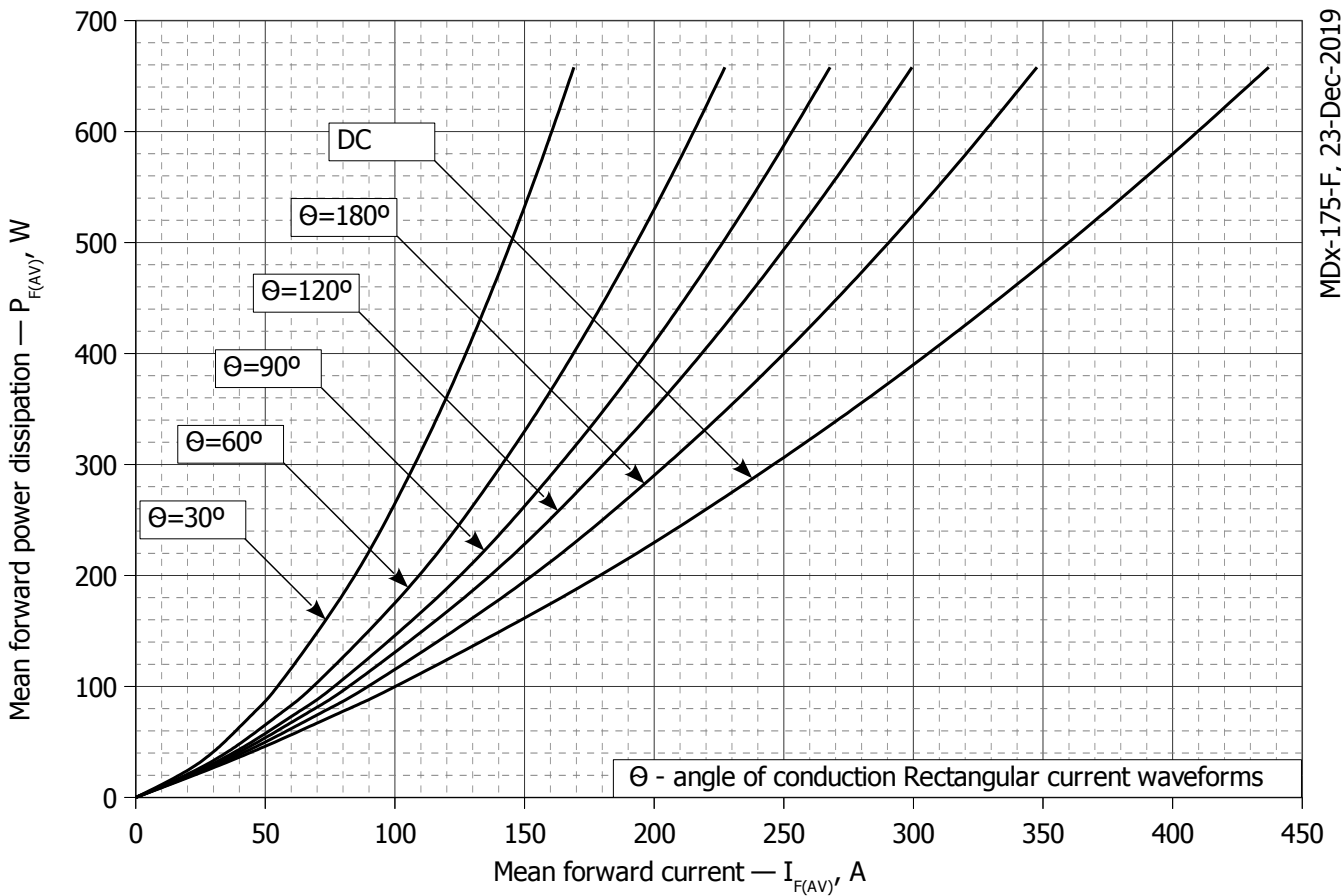


Fig. 8 – Mean forward power dissipation $P_{F(AV)}$ vs. mean forward current $I_{F(AV)}$ for rectangular current waveforms at different conduction angles and for DC ($f=50\text{Hz}$, DSC)

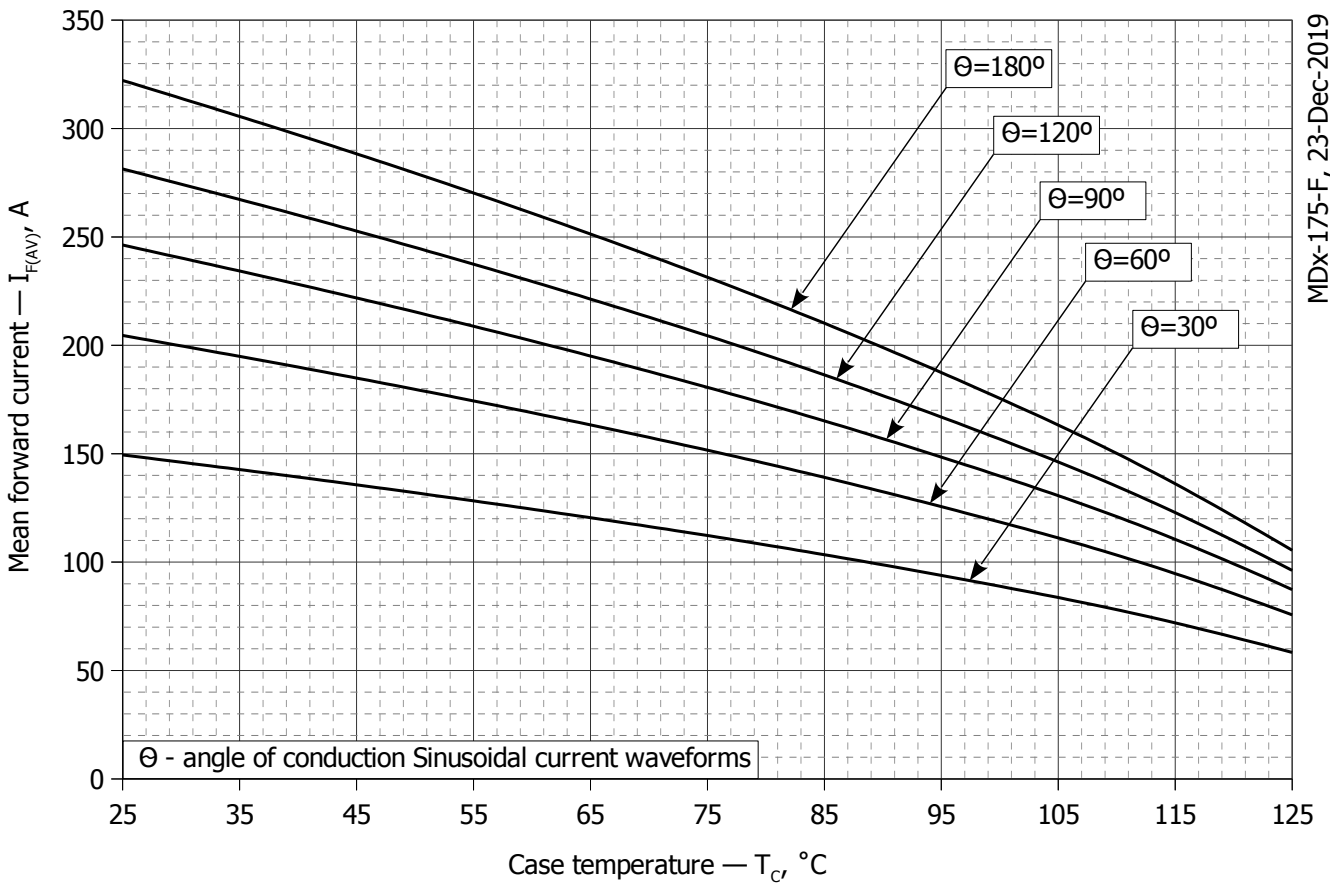


Fig. 9 – Mean forward current I_{FAV} vs. case temperature T_C for sinusoidal current waveforms at different conduction angles ($f=50Hz$, DSC)

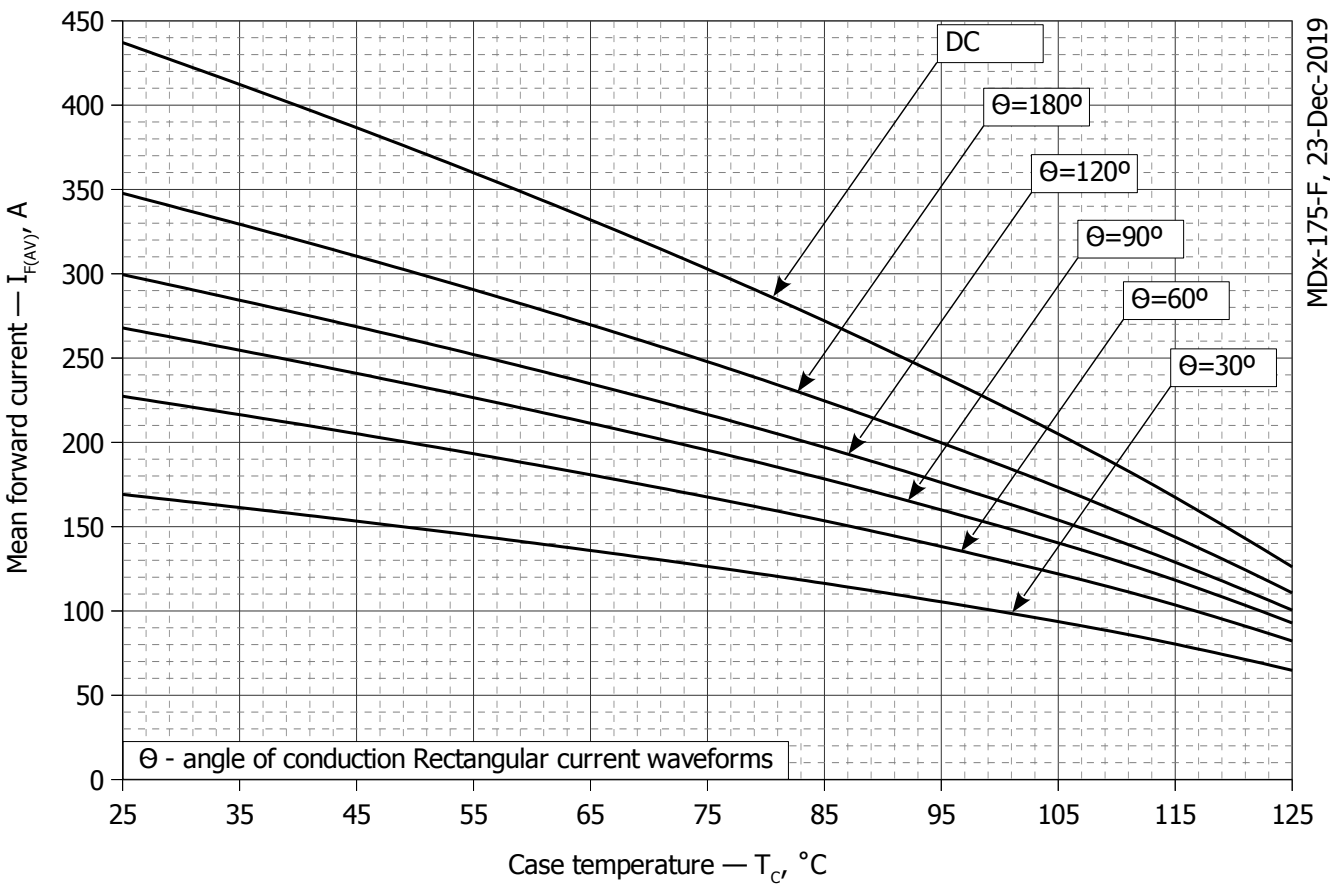


Fig. 10 - Mean forward current I_{FAV} vs. case temperature T_C for rectangular current waveforms at different conduction angles and for DC ($f=50Hz$, DSC)

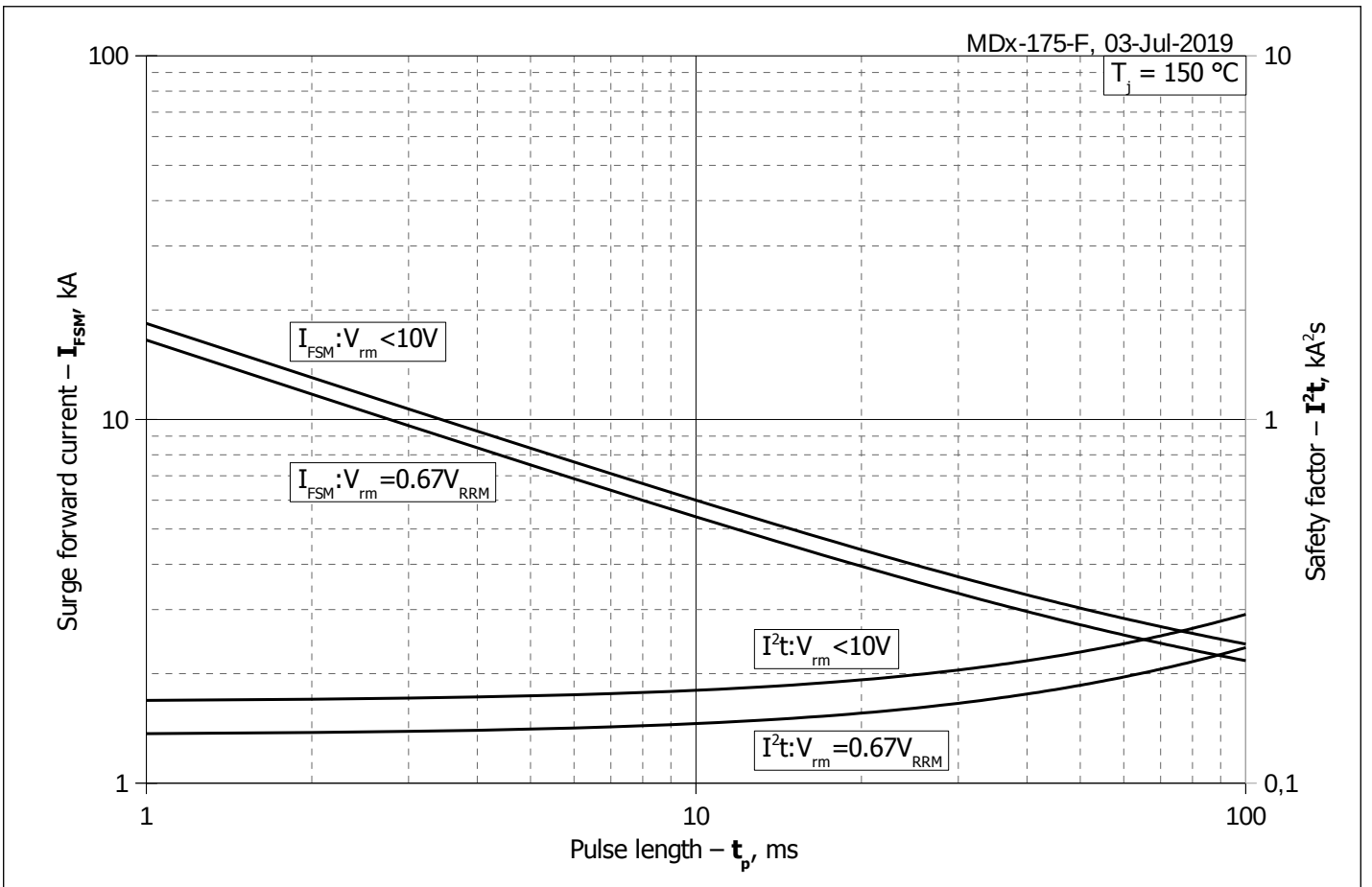


Fig. 11 – Maximum surge forward current I_{FSM} and safety factor I^2t vs. pulse length t_p

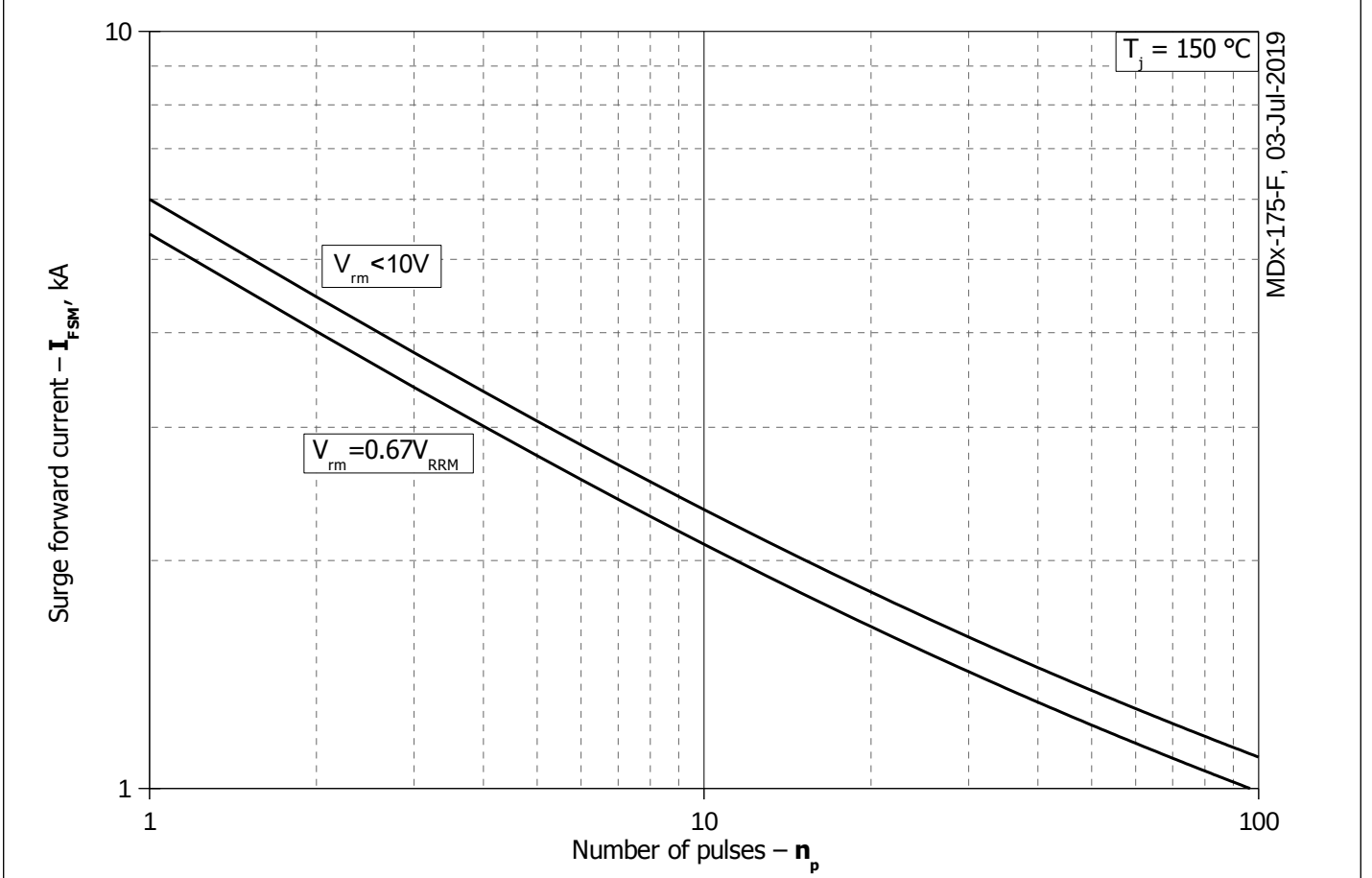


Fig. 12 - Maximum surge forward current I_{FSM} vs. number of pulses n_p